NCE P-Channel Enhancement Mode Power MOSFET

DESCRIPTION

The NCE2305 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

GENERAL FEATURES

• $V_{DS} = -8V, I_D = -4.1A$

 $R_{DS(ON)} < 118m\Omega @ V_{GS} = -1.8V$

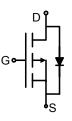
 $R_{DS(ON)}$ <81m Ω @ V_{GS} =-2.5V

 $R_{DS(ON)}$ < 68m Ω @ V_{GS} =-4.5V

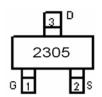
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- PWM applications
- Load switch
- ●Power management



Schematic diagram



Marking and pin Assignment



SOT-23 top view

Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2305	NCE2305	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (TA=25℃unless otherwise noted)

	,			
Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	-8	V	
Gate-Source Voltage	V _G S	±8	V	
Drain Current -Continuous	I _D	-4.1	Α	
Drain Current -Pulsed (Note 1)	I _{DM}	-15	Α	
Maximum Power Dissipation	P _D	1.7	W	
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	74	°C/W
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Electrical Characteristics (TA=25°Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-8			V



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NCE2305

Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-8V,V _{GS} =0V			-1	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±8V,V _{DS} =0V			±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =-250μA -0.			-1.0	V	
		V _{GS} =-4.5V, I _D =-3.5A		42	68		
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-2.5V, I _D =-3A		55	81	mΩ	
		V _{GS} =-1.8V, I _D =-2A			118		
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-3.5A		8.5		S	
Dynamic Characteristics (Note4)							
Input Capacitance	C _{lss}	V _{DS} =-4V,V _{GS} =0V,		740		PF	
Output Capacitance	Coss	F=1.0MHz		290		PF	
Reverse Transfer Capacitance	C _{rss}	1 -1.000112		190		PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	$t_{d(on)}$			12		nS	
Turn-on Rise Time	t _r	V _{DD} =-4V,I _D =-3.3A ,		35		nS	
Turn-Off Delay Time	$t_{d(off)}$	R_L =-1.2 Ω , V_{GEN} =-4.5 V , R_g =1 Ω		30		nS	
Turn-Off Fall Time	t _f			10		nS	
Total Gate Charge	Qg			7.8		nC	
Gate-Source Charge	Q _{gs}	V _{DS} =-4V,I _D =-4.1A,V _{GS} =-4.5V		1.2		nC	
Gate-Drain Charge	Q_{gd}			1.6		nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =-1.6A			-1.2	V	
Diode Forward Current (Note 2)	Is				1.6	Α	

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

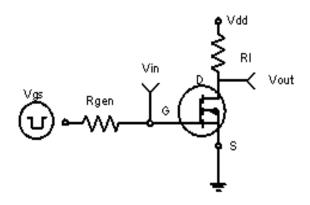


Figure 1:Switching Test Circuit

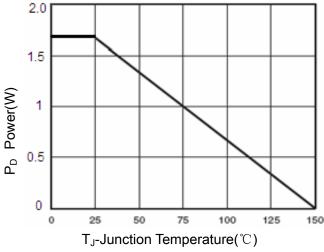


Figure 3 Power Dissipation

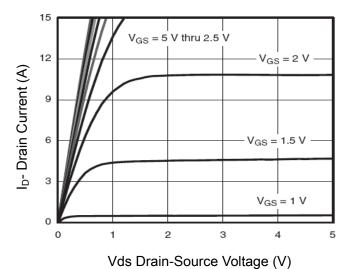


Figure 5 Output CHARACTERISTICS

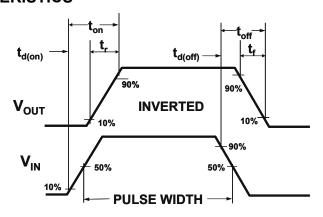


Figure 2:Switching Waveforms

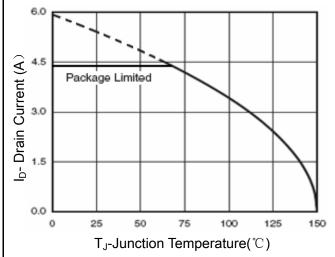


Figure 4 Drain Current

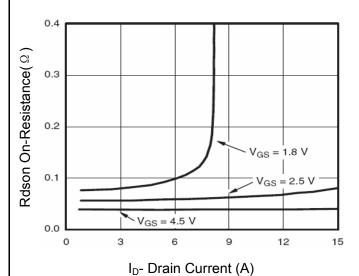
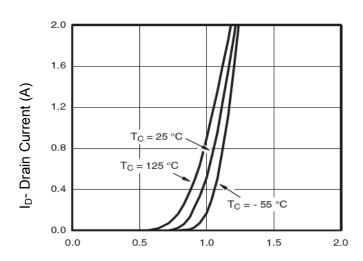
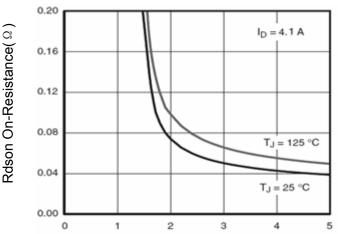


Figure 6 Drain-Source On-Resistance



Vgs Gate-Source Voltage (V)





Vgs Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs

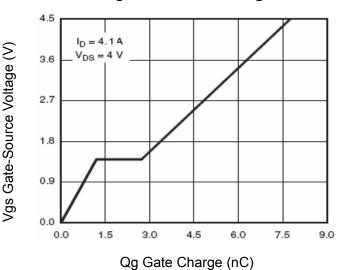


Figure 11 Gate Charge

1.6 Vgs=4.5V

1.4 1.2 1.0 0.8

T_J-Junction Temperature(°C)

75

0

25

50

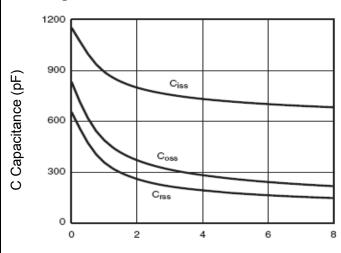
Figure 8 Drain-Source On-Resistance

100

125

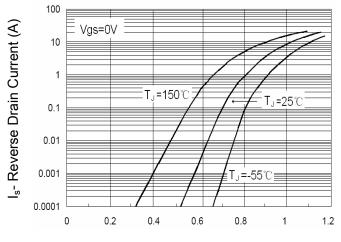
150

175



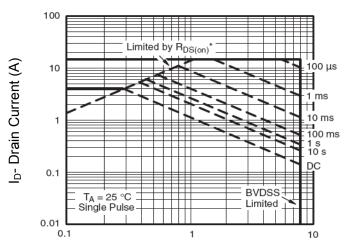
Vds Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)

Figure 13 Safe Operation Area

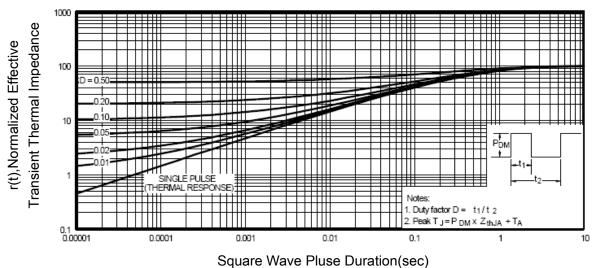
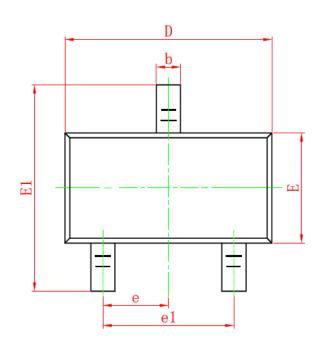
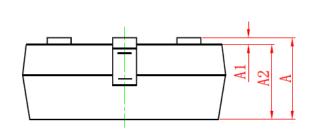


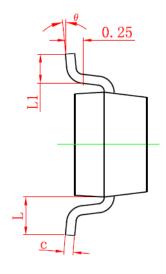
Figure 14 Normalized Maximum Transient Thermal Impedance

SOT-23 PACKAGE INFORMATION

Dimensions in Millimeters (UNIT:mm)







Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
Α	0.900	1.150		
A 1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250 2.550			
е	0.950TYP			
e1	1.800 2.000			
L	0.550REF			
L1	0.300 0.500			
θ	0° 8°			

NOTES

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

Pb Free Product

NCE2305

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